REG. NO .: 20BCD7160

Title of the experiment :- Hall effect

Objective:

To determine the Hall cofficient of the given semiconductor crystal (Germanium)

Equipment List:

- · Electromagnet and power supply.
- · Semiconductor crystal
- · Current Source and Ammeter
- · voltmeter
- · Connecting wires

Formula:

The Hall-coefficient is given by,

$$R_{H} = \frac{V_{H}.t}{IB}$$
 (v.m/A.tesla)

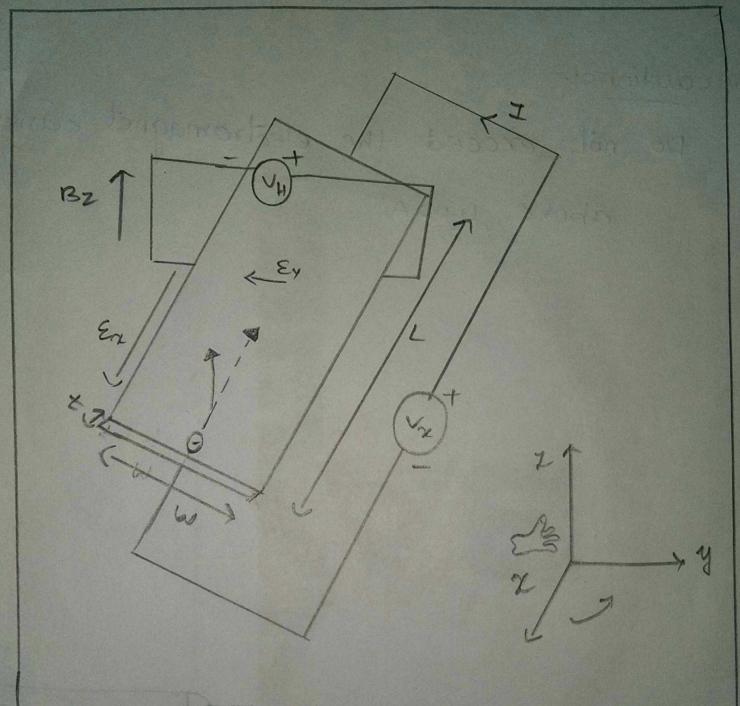
Here VH: Hall voltage developed

I: Eurrent passing through the sample

B: Applied magnetic field

t: Thickness of the semiconductor crystal

VH = VHB - VHO (VHB-in presence of magnetic field,



Schematics of Hall effect set up for electrons

Calculations :-

Table 1:- += 0.5mm, V+0 = 191.3 mv, I = 5 mA

= 0.1911					
magnetizing	-Hall voltage		magnetic	RH	
			field (B)		
current (A)	VHB	VH = VHB-VHO	Tesla		
1.00	128.1	VH=128-1-19-191 = 127-909	80×10-4	1598	
1.75	89.7	VH = 89.7 - 0.191	144 × 104	621	
2.50	47.4	VH = 47.4-0191 = 47.209	211×104	223	
3.25	21.8	VH= 21.8-0.191 = 21.609	260×104	830	
4.00	2.8	VH = 2.2-0.191 = 2.669	298×104	8:72 875-5 ×10 ²	

Mean RH = 656.144

$$\frac{1}{18} = \frac{127.909 \times 0.5 \times 10^{3}}{5 \times 10^{3} \times 80 \times 10^{4}} = \frac{63.9545 \times 10^{4}}{5 \times 80}$$

$$= 0.1598 \times 10^{4}$$

Table 2: Applied magnetic field B = 80×104 Tesla

Input current to the sample	-Hall voltage		RH
(ma)	VHB.	VH = VHB - VHO	
7	135.0	VH = 135-0.191 = 134.809	1685
4	91.0	VH = 91 - 0.191 = 90.809	1135
3	65.0	$V_{H} = 65 - 0.191$ $= 64.809$	810
2	29.0	$V_{H} = 29 - 0.191$ = 28.809	36

Mean RH = 916.5

$$\frac{+0}{1.8} = \frac{v_{H.t}}{1.8} = \frac{134.809 \times 0.5 \times 10^{15}}{52.00 \times 10^{15}} = \frac{67.4045}{400 \times 10^{4}} = \frac{67.400}{400 \times 10^{4}} = \frac{67.4045}{400 \times 10^{4}} = \frac{67.400}{400 \times 10^{4}} = \frac{67.4045}{400 \times 10^{4}} = \frac{67.4045}{400 \times 10^{4}} = \frac{67.400}{400 \times 10^{4$$

$$\frac{3}{18} = \frac{1135}{18} = \frac{64.869 \times 0.5 \times 10^{3}}{5 \times 10^{3} \times 80 \times 10^{4}} = \frac{22.4045}{400 \times 10^{4}} = \frac{20.0810 \times 10^{4}}{100 \times 10^{4}} = \frac{1135}{100 \times 10^{4}} = \frac{1135}$$

Precautions:-

Do not exceed the electromagnet current above 4.00 A

Result:

- 1. The Hall coefficient of the given semiconductor crystal was found to be 656.144
- 2. The Hall coefficient of the given semiconductor crystal was found to be 916.5